TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX08FT, TC74VCX08FK

Low-Voltage Quad 2-Input AND Gate with 3.6-V Tolerant Inputs and Outputs

The TC74VCX08FT/FK is a high-performance CMOS 2-input AND gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

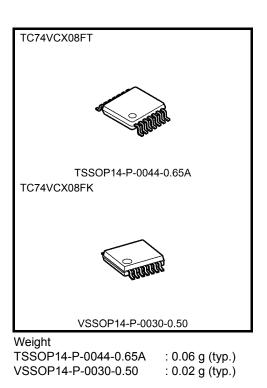
It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

All inputs are equipped with protection circuits against static discharge.

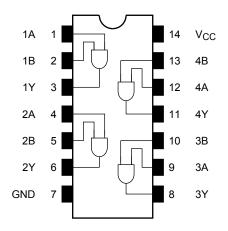
Features (Note)

- Low-voltage operation: V_{CC} = 1.2 to 3.6 V
- High-speed operation: $t_{pd} = 2.8 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
 - : $t_{pd} = 3.7 \text{ ns} (\text{max}) (\text{V}_{CC} = 2.3 \text{ to } 2.7 \text{ V})$
 - $t_{pd} = 7.4 \text{ ns} (\text{max}) (\text{V}_{\text{CC}} = 1.65 \text{ to } 1.95 \text{ V})$
 - $t_{pd} = 14.8 \text{ ns} (\text{max}) (V_{CC} = 1.4 \text{ to } 1.6 \text{ V})$
 - $t_{pd} = 37.0 \text{ ns} (max) (V_{CC} = 1.2 \text{ V})$
- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA} \text{ (min)} (V_{CC} = 3.0 \text{ V})$
 - $: I_{OH}/I_{OL} = \pm 18 \text{ mA} (\text{min}) (V_{CC} = 2.3 \text{ V})$
 - $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.65 \text{ V})$ $: I_{OH}/I_{OL} = \pm 2 \text{ mA (min)} (V_{CC} = 1.4 \text{ V})$
- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200$ V
 - Human body model $\ge \pm 2000 \text{ V}$
- Package: TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs

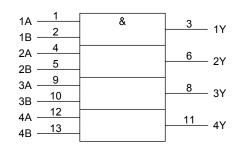
Note: Electrical Characteristics of Vcc=1.5±0.1V and 1.2V apply only to products whose Lot Code is over "3 12" .



Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inp	uts	Outputs		
А	В	Y		
L	L	L		
L	Н	L		
Н	L	L		
Н	Н	Н		

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5 to 4.6	V	
DC input voltage	V _{IN}	-0.5 to 4.6	V	
		-0.5 to 4.6 (Note 2)		
DC output voltage	V _{OUT}	–0.5 to V _{CC} + 0.5 (Note 3)	V	
Input diode current	IIК	-50	mA	
Output diode current	I _{OK}	±50 (Note 4)	mA	
DC output current	IOUT	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	–65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2:
$$V_{CC} = 0 V$$

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	1.2 to 3.6	V
Input voltage	V _{IN}	-0.3 to 3.6	V
Output voltage	Vout	0 to 3.6 (Note 2)	V
Output voltage	V001	0 to V_{CC} (Note 3)	v
		±24 (Note 4)	
Output current	1 /1	±18 (Note 5)	
	IOH/IOL	±6 (Note 6)	mA
		±2 (Note 7)	
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Note 4: $V_{CC}=$ 3.0 to 3.6 V $\,$

Note 5: $V_{CC} = 2.3$ to 2.7 V

Note 6: $V_{CC} = 1.65$ to 1.95 V

Note 7: $V_{CC} = 1.4$ to 1.6 V

Note 8: $V_{IN}=0.8$ to 2.0 V, $V_{CC}=3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characte	ristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH			2.7 to 3.6	2.0		v
Input voltage	L-level	VIL		_	2.7 to 3.6	—	0.8	v
H-level		VIN = VIH	I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_		
	V _{OH}		I _{OH} = -12 mA	2.7	2.2			
				I _{OH} = -18 mA	3.0	2.4		V
				I _{OH} = -24 mA	3.0	2.2		
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level	Max		I _{OL} = 12 mA	2.7	_	0.4	
	L-level	V _{OL}		I _{OL} = 18 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage curr	rent	I _{IN}	V _{IN} = 0 to 3.6 V	·	2.7 to 3.6	_	±5.0	μA
Power-off leakage	current	IOFF	V_{IN} , $V_{OUT} = 0$ to 3.6	V	0	_	10.0	μA
Quioscont augebu	ourront	las	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6		20.0	
Quiescent supply	current	Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.7 to 3.6		±20.0	μA
Increase in I _{CC} pe	er input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	

DC Characteristics (Ta = -40 to 85° C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteri	stics	Symbol	Test C	ondition		Min	Max	Unit
		,			V _{CC} (V)			
Input voltage	H-level	VIH	—		2.3 to 2.7	1.6		V
input voltage	L-level	VIL	-	_	2.3 to 2.7	—	0.7	v
H-level Output voltage			I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2			
	H-level	VOH	V _{IN} = V _{IH}	I _{OH} = -6 mA	2.3	2.0	_	V
				I _{OH} = -12 mA	2.3	1.8	_	
				I _{OH} = -18 mA	2.3	1.7	_	
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 100 μA	2.3 to 2.7	—	0.2	
	L-level	V _{OL}		$I_{OL} = 12 \text{ mA}$	2.3	—	0.4	
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		2.3 to 2.7	—	±5.0	μA
Power off leakage of	current	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply c	urront		$V_{IN} = V_{CC}$ or GND		2.3 to 2.7	_	20.0	
Quiescent supply c		Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.3 to 2.7	_	±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.65 V \leq V_{CC} < 2.3 V)

Characteri	stics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH	_	_		$\begin{array}{c} 0.65 \times \\ V_{CC} \end{array}$	_	V
input voitage	L-level	VIL	_		1.65 to 2.3		$0.2 \times V_{CC}$	v
H-level	H-level	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -100 μA	1.65 to 2.3	V _{CC} - 0.2	_	v
Output voltage				I _{OH} = -6 mA	1.65	1.25	_	
·	L-level		$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	1.65 to 2.3	_	0.2	
	L-level	V _{OL}		I _{OL} = 6 mA	1.65	_	0.3	
Input leakage curre	nt	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.65 to 2.3	_	±5.0	μA
Power-off leakage	current	IOFF	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0	_	10.0	μA
Quiesest suggly sugget		laa	$V_{IN} = V_{CC} \text{ or } GND$		1.65 to 2.3		20.0	
Quiescent supply c		Icc	$V_{CC} \le V_{IN} \le 3.6 V$		1.65 to 2.3	_	±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.4 V \leq V_{CC} < 1.65 V)

Characteri	stics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH	_	_		$0.65 \times V_{CC}$	_	V
input voltage	L-level	VIL	_		1.4 to 1.65	_	$0.05 \times V_{CC}$	v
H-level	Vон	V _{IN} = V _{IH}	I _{OH} = -100 μA	1.4 to 1.65	V _{CC} - 0.2	_		
Output voltage				$I_{OH} = -2 \text{ mA}$	1.4	1.05	_	V
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.4 to 1.65		0.05	
	L-level	VOL	VIN = VIH OL VIL	$I_{OL} = 2 \text{ mA}$	1.4	_	0.35	
Input leakage curre	nt	I _{IN}	$V_{IN} = 0$ to 3.6 V	V _{IN} = 0 to 3.6 V			±5.0	μA
Power-off leakage	current	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0		10.0	μA
Quiescent supply c	urrent		$V_{IN} = V_{CC}$ or GND		1.4 to 1.65		20.0	
Quiescent supply c		Icc	$V_{CC} \le V_{IN} \le 3.6 V$		1.4 to 1.65		±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.2 V \leq V_{CC} < 1.4 V)

Characteri	stics	Symbol	Test Condition V _{CC} (V)		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH	_		1.2 to 1.4	0.8 × V _{CC}		V
input voitage	L-level	VIL	_		1.2 to 1.4	_	$0.05 \times V_{CC}$	v
Output voltage	H-level	V _{OH}	$V_{IN} = V_{IH}$	I _{OH} = -100 μA	1.2	V _{CC} - 0.1		V
	L-level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	1.2		0.05	
Input leakage curre	nt	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.2	_	±5.0	μA
Power-off leakage of	current	IOFF	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0	_	10.0	μA
Quiescent supply current			$V_{IN} = V_{CC}$ or GND		1.2	_	20.0	
Quiescent supply c		Icc	$V_{CC} \le V_{IN} \le 3.6 V$		1.2		±20.0	μA

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns) (Note 1)

Characteristics	Symbol	Test Condition		Min	Max	Unit	
		Ci = 15 pF R	$C_{I} = 15 pF, R_{I} = 2 k\Omega$	1.2	1.5	37.0	
	+		$C_{L} = 15 \mu r$, $R_{L} = 2 R_{2}$	1.5 ± 0.1	1.0	14.8	
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2		1.8 ± 0.15	1.5	7.4	ns
	чрн∟		$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	$\textbf{2.5}\pm\textbf{0.2}$	0.8	3.7	
				$\textbf{3.3}\pm\textbf{0.3}$	0.6	2.8	
			$C_{I} = 15 pF, R_{I} = 2 k\Omega$	1.2		1.5	
	+		$O_{L} = 10 \text{ pr}, \text{ KL} = 2 \text{ KM}$	1.5 ± 0.1	_	1.5	
Output to output skew	t _{osLH}	(Note 2)		1.8 ± 0.15	—	0.5	ns
	t _{osHL}		$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	2.5 ± 0.2		0.5	
				$\textbf{3.3}\pm\textbf{0.3}$	_	0.5	

Note 1: For $C_L = 50 \text{ pF}$, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Symbol Test Condition				Тур.	Unit
				$V_{CC}(V)$		
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	0.25	
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	0.6	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note)	3.3	0.8	
	V _{OLV}	$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	-0.25	v
Quiet output minimum dynamic V_{OL}		$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	-0.6	
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note)	3.3	-0.8	
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	1.5	
Quiet output minimum dynamic V_{OH}	VOHV	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Test Condition		Тур.	Unit
Input capacitance	C _{IN}	—		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$ (per gate)

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AC Test Circuit

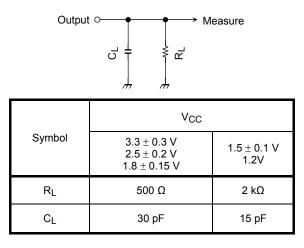
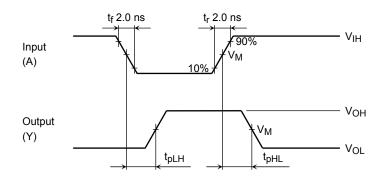


Figure 1

AC Waveform



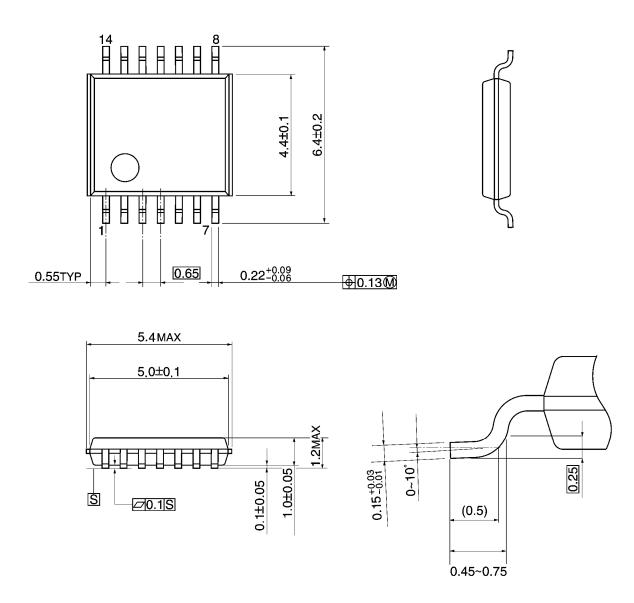
Symbol			V _{CC}		
Symbol	$3.3\pm0.3~V$	$2.5\pm0.2~\text{V}$	$1.8\pm0.15\;V$	$1.5\pm0.1~\text{V}$	1.2 V
VIH	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}
VM	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2

Figure 2 t_{pLH}, t_{pHL}

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



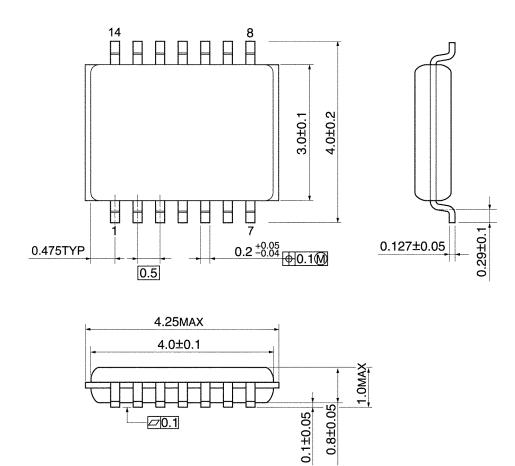
Weight: 0.06 g (typ.)

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Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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 00-8609-RDPP
 00-8722-RDPP
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